

# Nanoscale thermal transport

Lecture 5

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- 1. Wavelength, coherence length, mean free path, and relaxation time
- 2. Example Callaway model
- 3. Explore how different scattering mechanisms influence thermal conductivity versus temperature
  - a. Point defects
  - b. Interfaces
- 4. Explore low and high temperature limits
  - a. Lattice softening
- 5. Mean free path accumulation





**Relaxation time,**  $\tau$  (scalar): The time between scattering events of a phonon wave-packet.



**Group velocity,**  $v_g$  (vector): The speed and direction the wave-packet travels.



**Mean free path,**  $\Lambda = \mathbf{v_g} \tau$  (vector): The distance a phonon wavepacket travels before scattering.

 $\Lambda$  determines how closely defects must be space for them to significantly reduce thermal conductivity. For example, defects that are spaced significantly farther apart than the phonon wave-packets phonon-phonon scattering mean free path, will not significantly reduce the heat carried by the wave-packet.



**Wavelength**,  $\lambda$  (vector): The wavelength of the wavepacket.

 $\lambda$ , influences how strongly the phonon wave-packet will interact with a defect of a given physical size. This is intuitive when one remembers the scattering rate involves the real space Fourier transform of scattering potential (Lecture 4).

coherence length

**Coherence length** (vector): The distance over which the atomic vibrations are correlated to one another.

Ideal plane waves have an infinite coherence length. These do not exist in nature. In reality, there is a distance beyond which the vibration of atoms are uncorrelated.

# Callaway Modeling

We've derived each part of this model in previous lectures.The spectral version is listed here for reference.A similar procedure can be performed on a mode specific basis.

$$\kappa = \frac{1}{3} \int_{0}^{\omega_{\text{max}}} C(\omega) v_{\text{g}}(\omega)^2 \tau(\omega) \ d\omega$$

$$C(\omega) = \frac{3}{2\pi^2} \frac{\omega^4}{v_{\rm g} v_{\rm p}^2} \frac{\hbar^2}{k_{\rm B} T^2} \frac{e^{\hbar \omega/k_{\rm B} T}}{(e^{\hbar \omega/k_{\rm B} T} - 1)^2}$$

$$k_{\max} = \left(\frac{6\pi^2}{V}\right)^{1/3}$$

only acoustic modes
V: volume per primitive unit cell
all modes
V: volume per atom

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# **Dispersion relation:**

1) Debye

$$\omega = v_{\rm s} k \qquad \qquad \omega_{\rm max} = v_{\rm s} \, k_{\rm max}$$

$$v_{\rm g} = \frac{d\omega}{dk} = v_{\rm s}$$

$$v_{\rm s} = \left(\frac{1}{3v_{\rm L}^3} + \frac{2}{3v_{\rm T}^3}\right)^{-1/3}$$

 $v_{\rm p} = \frac{\omega}{k} = v_{\rm s}$ 

$$\omega = \omega_{\max} \sin\left(\frac{\pi}{2} \frac{k}{k_{\max}}\right) \qquad \omega_{\max} = \frac{2}{\pi} v_{s} k_{\max} \qquad v_{g} = \frac{d\omega}{dk} = v_{s} \cos\left(\frac{\pi}{2} \frac{k}{k_{\max}}\right) \qquad v_{p} = \frac{\omega}{k}$$
$$k = \frac{2}{\pi} k_{\max} \arcsin\left(\frac{\omega}{\omega_{\max}}\right)$$

Anderson, O. L. J. Phys. Chem. Solids 24, 909–917 (1963).

Materials values required to reproduce this model (roughly based on Si)

$$V = 4 \times 10^{-29} \text{ m}^{-3}$$
  

$$v_{s} = 6084 \text{ m/s}$$
  

$$\tau^{-1} = \tau_{pp}^{-1} + \tau_{pd}^{-1} + \tau_{b}^{-1}$$

 $\omega = v_{\rm s}k$ 

phonon-phonon scattering point defect scattering

boundary scattering

 $d = 0.1 \,\mu{\rm m}$ 

$$\tau_{\rm pp}^{-1} = \frac{\omega^2 T}{A v_{\rm s}^3} \exp\left(-\frac{B}{T}\right)$$

$$\tau_{\rm pd}^{-1} = \frac{V_{\rm atom}\omega^4}{4 \pi v_{\rm s}^3} f\left(1 - \frac{\Delta M}{M}\right)^2 \qquad \tau_{\rm b}^{-1} = \frac{v_{\rm s}}{d}$$

$$A = 0.135 \frac{\text{m}^3}{\text{Ks}^2}$$
$$B = 220 \text{ K}$$

$$M_{1} = 28.09 \times 10^{-3} \text{ kg/mol}$$
  

$$M_{2} = 30.97 \times 10^{-3} \text{ kg/mol}$$
  

$$\Delta M = M_{2} - M_{1}$$
  

$$M = fM_{1} + (1 - f)M_{2}$$
  

$$f = 0.005$$
  

$$V_{\text{atom}} = \frac{V}{2}$$

Tan, G. et al. ACS Energy Lett. **3**, 705–712 (2018). Hanus, R., Garg, A. & Snyder, G. J. Commun. Phys. 1, 78 (2018).

Low-T gives information about microstructural scattering
 High-T, κ ∝ T<sup>-1</sup> behavior stems from phonon-phonon scattering



Increased point defect scattering  $f = 0.005 \rightarrow 0.015$ 



Increased microstructural scattering  $d = 100 \text{ nm} \rightarrow 10 \text{ nm}$ 



Comparing the previous two models

increased point defect scattering vs. increased microstructural scattering



Callaway (spectral) model:

$$\kappa = \frac{1}{3} \int_{0}^{\omega_{\text{max}}} C(\omega) v_{\text{g}}(\omega)^2 \tau(\omega) \ d\omega$$



#### **Debye-Callaway model:**

$$\kappa_{\rm L} = k_{\rm B} \frac{(k_{\rm B} T)^3}{2\pi^2 v_{\rm S} \hbar^3} \int_0^{\theta_{\rm D}/T} \tau(x) \frac{x^4 e^x}{(e^x - 1)^2} dx \qquad \qquad x = \frac{\hbar\omega}{k_{\rm B} T}$$

on board

#### Low-temperature limit



Hanus, R., Garg, A. & Snyder, G. J. Phonon diffraction and dimensionality crossover in phonon-interface scattering. *Commun. Phys.* **1**, 78 (2018).

#### on board

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Hanus, R., Garg, A. & Snyder, G. J. Phonon diffraction and dimensionality crossover in phonon-interface scattering. *Commun. Phys.* **1**, 78 (2018).

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### High-temperature limit

Assert the following form of phonon-phonon scattering, and Debye dispersion

$$\tau_{\rm pp} = \left(\frac{6\pi^2}{V}\right)^{1/3} \frac{\overline{M} v_{\rm s}^3}{2k_{\rm B}\gamma^2 \omega^2 T}$$

Refs: Slack, G. A. & Galginaitis, S. *Phys. Rev.* **133**, (1964). Toberer, E. S., et al. *J. Mater. Chem.* **21**, 15843 (2011).

Make high temperature approximation ( $T > \Theta_D$ ) for  $C(\omega)$ 

 $C(\omega) \approx \frac{3 k_{\rm B} \omega^2}{2 \pi^2 v_{\rm s}^3}$ 



Hanus, R. *et al.* Lattice Softening Significantly Reduces Thermal Conductivity and Leads to High Thermoelectric Efficiency. *Adv. Mater.* **1900108**, 1900108 (2019). 18

# Phonon scattering vs. Elastic (lattice) softening



# When is softening expected to be important?

- 1. Anharmonic materials
- 2. High temperatures



Accumulation plots

$$\kappa = \frac{1}{3} \sum_{s} \int_{0}^{\omega_{\text{max}}} C(\omega) v_{\text{g}}(\omega) \Lambda(\omega) d\omega$$

If I know  $\Lambda(\omega)$ , then I can rewrite the integral over  $\omega$  to one over  $\Lambda$ . Note,  $\Lambda(\omega)$  usually decreases with increasing  $\omega$ . So we label  $\Lambda(\omega_{\text{max}}) = \Lambda_{\text{min}}$  and  $\Lambda(0) = \Lambda_{\text{max}}$ .

$$\kappa = \frac{1}{3} \sum_{s} \int_{\Lambda_{\text{max}}}^{\Lambda_{\text{min}}} C v_{\text{g}} \Lambda \left(\frac{d\Lambda}{d\omega}\right)^{-1} d\Lambda$$

Flip the limits, which spits out a negative sign, and package up the integrand into  $K_\Lambda$ 

$$\kappa = \int_{\Lambda_{\min}}^{\Lambda_{\max}} K_{\Lambda} \ d\Lambda \qquad \qquad K_{\Lambda} = -\frac{1}{3} \sum_{s} C \ v_{g} \Lambda \left(\frac{d\Lambda}{d\omega}\right)^{-1}$$

Now define the "Normalized accumulation function"

$$\alpha(\Lambda_{\alpha}) = \frac{1}{\kappa} \int_{\Lambda_{\min}}^{\Lambda_{\alpha}} K_{\Lambda} \, d\Lambda \qquad \text{plot from } \Lambda_{\alpha} = \Lambda_{\min} \text{ to } \Lambda_{\max}$$

Yang, F. & Dames, C. Mean free path spectra as a tool to understand thermal conductivity in bulk and 21 nanostructures. *Phys. Rev. B - Condens. Matter Mater. Phys.* **87**, 1–12 (2013).

#### Accumulation plots

Example



75% of the heat is carried by phonons with a mean free path less than 1000 nm in Si, and less than 5 nm in PbTe

Liu, Z., Mao, J., Liu, T.-H., Chen, G. & Ren, Z. MRS Bull. 43, 181–186 (2018).